
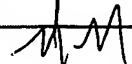
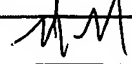
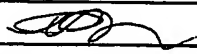



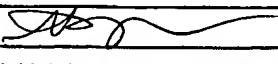


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FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT				Docket No.: AI 391 NP	International No.: PCT/JP05/12751	U.S. Serial No.: 10/551,918	
				Applicant(s): Hirokazu ASAHARA et al.			
				International Filing Date: July 11, 2005	U.S. Filing Date: October 5, 2005	Group Art Unit: To be assigned	
U.S. PATENT DOCUMENTS							
Examiner Initial		Document Number	Date	Name	Class	Sub-Class	Filing Date
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Sub-Class	Translation
	AI	2002-190620	07/05/2002	JAPAN			Abstract and Translation
	AJ	2000-077713	03/14/2000	JAPAN			Abstract and Translation
	AK	49-84383	08/13/1974	JAPAN			No
	AL						
	AM						
	AN						
OTHER (Including Author, Title, Date, Pertinent Pages, etc.)							
	AO						
Examiner 					Date Considered 10/25/02		
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		Applicant: Hirokazu ASAHARA et al.					
		International Filing Date: July 11, 2005		Group Art Unit: To Be Assigned			
U.S. PATENT DOCUMENTS							
Exam- iner Initial		Document Number	Date	Name	Class	Sub- Class	Filing Date
FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Sub- Class	Trans- lation
		09-129919	05/16/97	JAPAN			Abstract and computer translation
		11-121797	04/30/99	JAPAN			Abstract and computer translation
		2003-224297	08/08/03	JAPAN			Abstract and computer translation
OTHER (Including Author, Title, Date, Pertinent Pages, etc.)							
		Ken NAKAHARA et al. "Improved External Efficiency InGaN—Based Light-Emitting Diodes with Transparent Conductive Ga—Doped ZnO as p-Electrodes", Japanese Journal of Applied Physics, Vol. 43, No.2A, 2004, pp. L180—L182.					
Examiner 					Date Considered 10/25/05		
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							